NSN 5961-01-376-4989

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-376-4989 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 0.700 inches **Overall Diameter:** 0.085 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 working peak reverse voltage and 400.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 2.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 89954-312a3735 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No